AMENDMENTS TO THE CLAIMS

- 1. (Currently Amended) An in-plane switching mode liquid crystal display device, comprising:
 - a plurality of gate lines and data lines defining a plurality of pixels;
 - a driving device in each of the pixels;
 - a pixel electrode in each of the pixels; and
 - a common electrode completely overlapping a data line in width,
 - wherein the driving device is a thin film transistor comprising:
 - a gate electrode on a substrate;
 - an insulating layer over the gate electrode;
 - a semiconductor layer on the insulating layer;
 - a source electrode and a drain electrode on the semiconductor layer; and
 - a passivation layer over the source electrode, drain electrode and semiconductor layer,

<u>and</u>

wherein the pixel electrode is formed on the passivation layer.

- 2 (Cancelled)
- 3. (Cancelled)
- 4. (Currently Amended) The device of claim [[3]] 1, wherein the data lines are formed on the insulating layer.
- 5. (Currently Amended) The device of claim [[3]] 1, wherein the common electrode is formed on the passivation layer.
 - 6. (Cancelled)
 - 7. (Cancelled)

8. (Currently Amended) <u>An in-plane switching mode liquid crystal display device</u>, comprising:

a plurality of gate lines and data lines defining a plurality of pixels;

a driving device in each of the pixels;

a pixel electrode in each of the pixels; and

a common electrode completely overlapping a data line in width,

wherein the driving device is a thin film transistor comprising:

a gate electrode on a substrate;

an insulating layer over the gate electrode;

a semiconductor layer on the insulating layer;

a source electrode and a drain electrode on the semiconductor layer; and

a passivation layer over the source electrode, drain electrode and semiconductor layer,

<u>and</u>

The device of claim 3, wherein the passivation layer is formed of an organic material.

- 9. (Original) The device of claim 8, wherein the passivation layer is formed of one of BCB (Benzo-Cyclo-Butene) and photoacryl.
- 10. (Currently Amended) An in-plane switching mode liquid crystal display device, comprising:

a plurality of gate lines and data lines defining a plurality of pixels;

a driving device in each pixel;

at least one pixel electrode formed on a passivation layer in each pixel;

a first common electrode completely overlapping [[the]] a data line in width; and

at least one second common electrode in each pixel.

11. (Original) The device of claim 10, wherein a width of the first common electrode is larger than that of the second common electrode.

- 12. (Currently Amended) An in-plane switching mode liquid crystal display device, comprising:
 - a plurality of gate lines and data lines defining a plurality of pixels;
 - a first pixel electrode in a first pixel;
 - a first driving device in the first pixel;
 - a second pixel electrode in a second pixel;
 - a second driving device in the second pixel;
 - a passivation layer for insulating the first and second driving devices; and
- a first common electrode formed between the first and second pixel electrodes, and on the passivation layer,

wherein the passivation layer is formed of one of BCB (Benzo-Cyclo-Butene) and photoacryl.

- 13. (Original) The device of claim 12, wherein the first common electrode completely overlaps a data line.
 - 14. (Cancelled)
 - 15. (Original) The device of claim 12, further comprising:
- a second common electrode in the first pixel for forming a horizontal electric field with the first pixel electrode; and
- a third common electrode in the second pixel for forming a horizontal electric field with the second pixel electrode.
- 16. (Original) The device of claim 12, wherein a width of the first common electrode is larger than that of one of the second common electrode and the third common electrode.

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